

# UNIVERSAL ISM BAND FSK TRANSCEIVER MODULE

### **RFM12**

(the purpose of this spec covers mainly for the physical characteristic of the module, for register configure and its related command info please refer to RF12 data sheets)

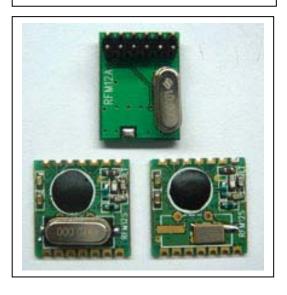
#### **General Introduction**

RFM12 is a low costing ISM band transceiver module implemented with unique PLL. It works signal ranges from 315/433/868/915MHZ bands, comply with FCC, ETSI regulation. The SPI interface is used to communicate with microcontroller for parameter setting.

#### **Features:**

- · Low costing, high performance and price ratio
- Tuning free during production
- PLL and zero IF technology
- Fast PLL lock time
- High resolution PLL with 2.5 KHz step
- High data rate (up to 115.2 kbps with internal demodulator, with external RC filter highest data rate is 256 kbps)
- · Differential antenna input
- Automatic antenna tuning
- Programmable TX frequency deviation (from 15 to 240 KHz)
- Programmable receiver bandwidth (from 67 to 400 kHz)
- Analog and digital signal strength indicator (ARSSI/DRSSI)
- AFC
- DQD
- · Internal data filtering and clock recovery
- RX synchron pattern recognition
- SPI interface
- Clock and reset signal output for external MCU use
- 16 bit RX Data FIFO
- Two 8 bit TX data registers
- 10MHz crystal for PLL timing
- · Wakeup timer
- 2.2V 5.4V power supply
- · Low power consumption
- Standby current less than 0.3uA

#### RFM12

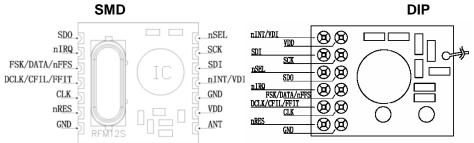




# **Typical Application:**

- Remote control
- Remote sensor
- Wireless data collection
- Home security system
- Toys
- Tire pressure monitoring system

### **Pin Definition:**



definition	Туре	Function	
nINT/VDI	DI/ DO	Interrupt input (active low)/Valid data indicator	
VDD	S	Positive power supply	
SDI	DI	SPI data input	
SCK	DI	SPI clock input	
nSEL	DI	Chip select (active low)	
SDO	DO	Serial data output with bus hold	
nIRQ	DO	Interrupts request output (active low)	
FSK/DATA/nFFS	DI/DO/DI	Transmit FSK data input/ Received data output (FIFO not used)/ FIFO	
		select	
DCLK/CFIL/FFIT	DO/AIO/DO	Clock output (no FIFO )/ external filter capacitor(analog mode)/ FIFO	
		interrupts(active high)when FIFO level set to 1, FIFO empty	
		interruption can be achieved	
CLK	DO	Clock output for external microcontroller	
nRES	DIO	Reset output (active low)	
GND	S	Power ground	



# **Electrical Parameter:**

### Maximum (not at working mode)

	<u> </u>			
symbol	parameter	minimum	maximum	Unit
$V_{dd}$	Positive power supply	-0.5	6.0	V
V <sub>in</sub>	All pin input level	-0.5	Vdd+0.5	V
l <sub>in</sub>	Input current except power	-25	25	mA
ESD	Human body model		1000	V
T <sub>st</sub>	Storage temperature	-55	125	$^{\circ}$ C
T <sub>Id</sub>	Soldering temperature(10s)		260	$^{\circ}\!\mathbb{C}$

Recommended working range

symbol	parameter	minimum	maximum	Unit
$V_{dd}$	Positive power supply	2.2	5.4	V
T <sub>op</sub>	Working temperature	-40	85	$^{\circ}$ C

## **DC** characteristic

symbol	parameter	Remark	minimum	typical	maximum	Unit
I <sub>dd_TX_0</sub>	Supply current	315,433MHz band		13		mA
	(TX mode, P <sub>out</sub> = 0dBm)	868MHz band		16		
		915MHz band		17		
I <sub>dd_TX_PMAX</sub>	Supply current	315,433MHz band		21		mA
	(TX mode, $P_{out} = P_{max}$ )	868MHz band		24		
		915MHz band		25		
I <sub>dd_RX</sub>	Supply current	315,433MHz band		10		mA
	(RX mode)	868MHz band		12		
		915MHz band		13		
I <sub>x</sub>	Stand by current	Crystal and base band		3. 0	3. 5	mA
		on				
I <sub>pd</sub>	Sleep mode current	All blocks off		0.3		uA
I <sub>lb</sub>	Low battery detection			0.5		uA
V <sub>Ib</sub>	Low battery step	0.1V per step	2.2		5.3	V
V <sub>lba</sub>	Low battery detection			75		mV
	accuracy					
Vil	Low level input				0.3*V <sub>dd</sub>	V
V <sub>ih</sub>	High level input		0.7*V <sub>dd</sub>			V
I <sub>ii</sub>	Leakage current	V <sub>il</sub> =0V	-1		1	uA
I <sub>ih</sub>	Leakage current	V <sub>ih</sub> =V <sub>dd</sub> , V <sub>dd</sub> =5.4V	-1		1	uA
Vol	Low level output	I <sub>ol</sub> =2mA			0.4	V
V <sub>oh</sub>	High level output	I <sub>oh</sub> =-2mA	V <sub>dd</sub> -0.4			V



# AC characteristic

symbol	parameter	remark	min	typical	max	Unit
f <sub>ref</sub>	PLL frequency		8	10	12	MHz
	frequency	315 MHz band,2.5KHz step	310.24		319.75	
$f_{LO}$	(10MHz crystal	433 MHz band,2.5KHz step	430.24		439.75	MHz
	used)	868 MHz band,5KHz step	860.48		879.51	
		915 MHz band,7.5KHz step	900.72		929.27	
	frequency	315 MHz band,2.5KHz step	248.19		255.80	
$f_{LO}$	(8MHZ crystal	433 MHz band,2.5KHz step	344.19		351.80	MHz
	used)	868 MHz band,5KHz step	688.38		703.61	
		915 MHz band,7.5KHz step	720.57		743.41	
	frequency	315 MHz band,2.5KHz step	372.28		383.71	
$f_{LO}$	(12MHZ crystal	433 MHz band,2.5KHz step	516.28		527.71	MHz
	used)	868 MHz band,5KHz step	1032.5		1055.4	
		915 MHz band,7.5KHz step	1080.8		1115.1	
BW	Receiver	1	60	67	75	
	bandwidth	2	120	134	150	
		3	180	200	225	KHz
		4	240	270	300	
		5	300	350	375	
		6	360	400	450	
t <sub>lock</sub>	PLL lock time	After 10MHz step hopping,		20		us
		frequency error <10 kHz				
BR	Data rate	With internal digital	0.6		115.2	kbps
		demodulator				
BR <sub>A</sub>	Data rate	With external RC filter			256	kbps
P <sub>min</sub>	sensitivity	BW=134KHz,BR=1.2kbps		-102	-96	dBm
AFCrange	AFC working range	df <sub>FSK</sub> FSK deviation in the		0.8*		
		received signal		df <sub>FSK</sub>		
RSA	RSSI accuracy			±5		dB
RS <sub>R</sub>	RSSI range			46		dB
C <sub>ARSSI</sub>	ARSSI filter			1		nF
RS <sub>STEP</sub>	RSSI			6		dB
	programmable step					
RS <sub>RESP</sub>	DRSSI response	RSSI output high after		500		us
	time	valid , CARRSI=5nF				

#### **AC** characteristic(Transmitter)

symbol	parameter	remark	min	typical	max	Unit
P <sub>max</sub>	Available output power with	315/433MHZ band		8		dbm
	optimal antenna impedance	868/915MHZ band		0		
Pout	Typical output power	Selectable in 3 dB	P <sub>max</sub> -21		P <sub>max</sub>	dbm
		steps				

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Co	Output capacitance	In low bands	2	2.6	3.2	pf
	(set by the automatic antenna	In high bands	2.1	2.7	3.3	
	tuning circuit)					
Qo	Quality factor of the output	In low bands	13	15	17	
	capacitance	In high bands	8	10	12	
Lout	Output phase noise	100 kHz from carrier			-75	dbc/HZ
		1 MHz from carrier			-85	
BR	FSK bit rate				256	kbps
df <sub>fsk</sub>	FSK frequency deviation	Programmable in 15	15		240	kHZ
		kHz steps				

AC characteristic(Turn-on/Turnaround timings)

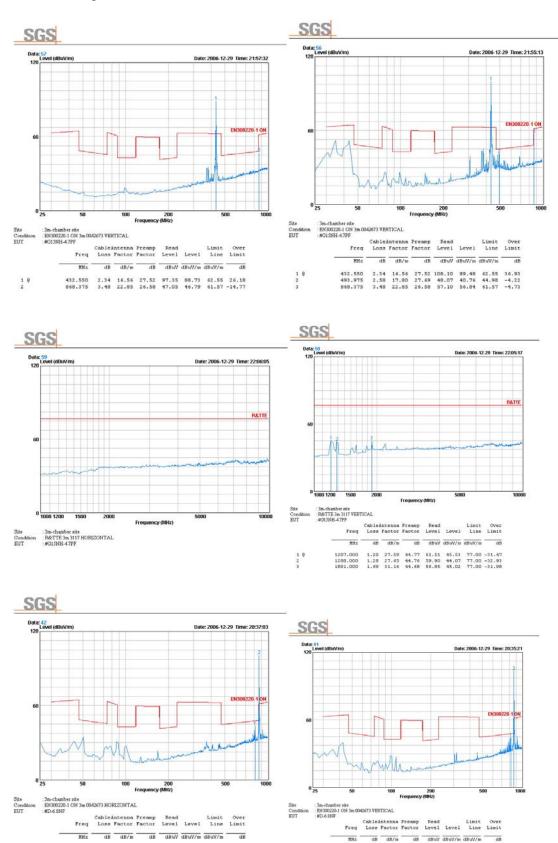
symbol	parameter	remark	min	typical	max	Unit
T <sub>st</sub>	Crystal oscillator startup	Crystal ESR < 100		71	5	ms
	time					
T <sub>tx_rx_XTAL_ON</sub>	Transmitter - Receiver	Synthesizer off, crystal		450		us
	turnover time	oscillator on				
$T_{rx\_tx\_XTAL\_ON}$	Receiver - Transmitter	Synthesizer off, crystal		350		us
	turnover time	oscillator on				
$T_{tx\_rx\_SYNT\_ON}$	Transmitter - Receiver	Synthesizer on, crystal		425		us
	turnover time	oscillator on				
T <sub>rx_tx_SYNT_ON</sub>	Receiver - Transmitter	Synthesizer on, crystal		300		us
	turnover time	oscillator on				
C <sub>xI</sub>	Crystal load	Programmable in 0.5 pF steps,	8.5		16	pf
	capacitance	tolerance+/- 10%				
t <sub>POR</sub>	Internal POR timeout	After V <sub>dd</sub> has reached 90% of			100	ms
		final value				
t <sub>PBt</sub>	Wake-up timer clock	Calibrated every 30 seconds	0.96		1.05	ms
	period					
C <sub>in, D</sub>	Digital input apacitance				2	pf
t <sub>r, f</sub>	Digital output rise/fall	15pF pure capacitive load			10	ns
	time					

Field testing range

	9 :9 -	
Band	Test condition	Distance
315MHz band	Receiver bandwidth=67KHz,data rate =1.2kbps,Transmitter frequency	
	deviation =45KHZ (matches with RFM12) in free open area	
433MHz band	Receiver bandwidth =67KHz, data rate=1.2kbps, transmitter frequency	>150M
	deviation =45KHZ (matches with RFM12) In free open area	
868MHz band	Receiver bandwidth=67KHz,data rate =1.2kbps,Transmitter frequency	>100M
	deviation =45KHZ (matches with RFM12) in free open area	
915MHz band	Receiver bandwidth=67KHz,data rate =1.2kbps,Transmitter frequency	>100M
	deviation =45KHZ (matches with RFM12) in free open area	



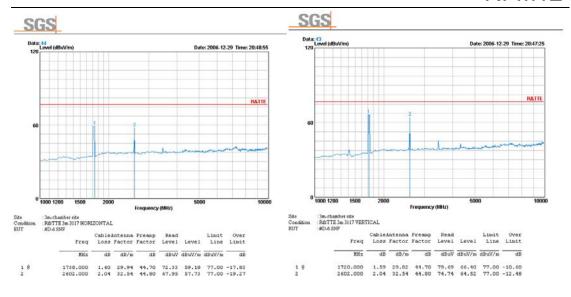
# **SGS** Reports



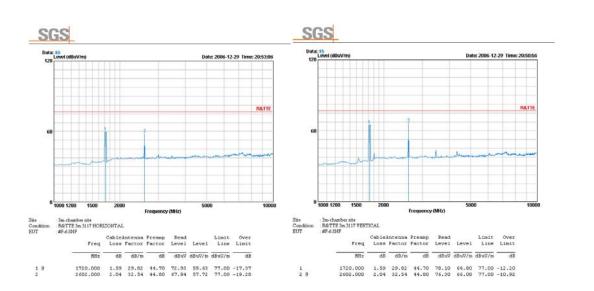
820,600 3.30 22.33 26.84 45.80 44.59 47.82 -3.24 868.375 3.48 22.85 26.58 103.62 103.36 61.57 41.79

816.700 3.28 22.29 26.86 44.32 43.04 47.80 -4.76 868.375 3.40 22.85 26.58 101.04 100.78 61.57 39.21

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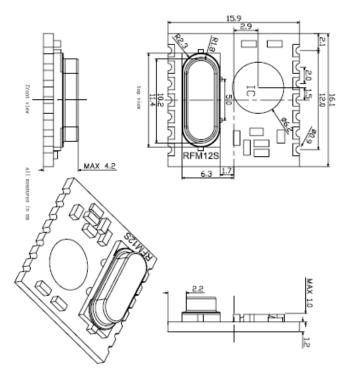
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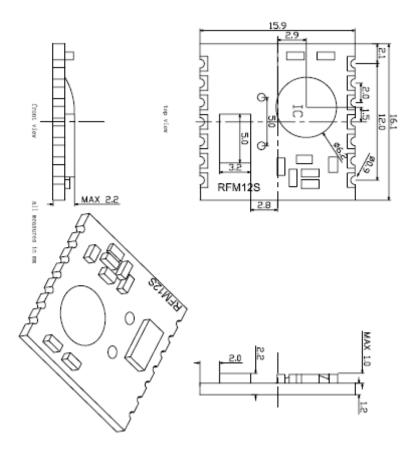
# **Mechanical Dimension**

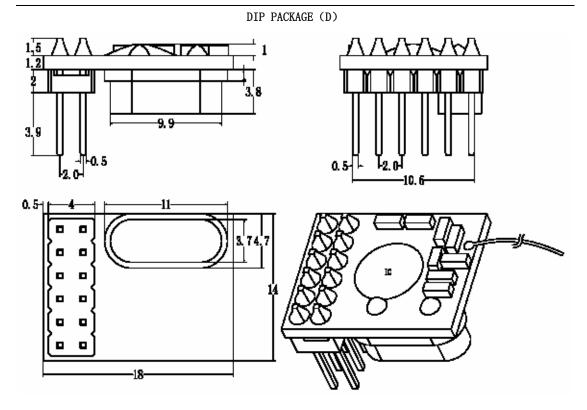
(units in mm)

#### SMD PACKAGE (S1)



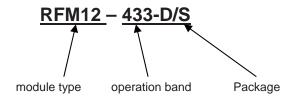
SMD PACKAGE (S2)





## **Module Model Definition**

model=module-operation band



example: 1, RFM12 module at 433MHz band, DIP: RFM12-433-D.

2, RFM12 module at 868MHZ band, SMD, thickness at 4.2mm: RFM12-868-S1  $_{\circ}$ 

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# RFM12

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